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Author Correction: Superconducting Diamond on Silicon Nitride for Device Applications

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In Figure 4, the 'RCA-1 cleaned' and 'Solvent cleaned' plots are labelled incorrectly. The correct Figure 4 appears below as Figure 1.

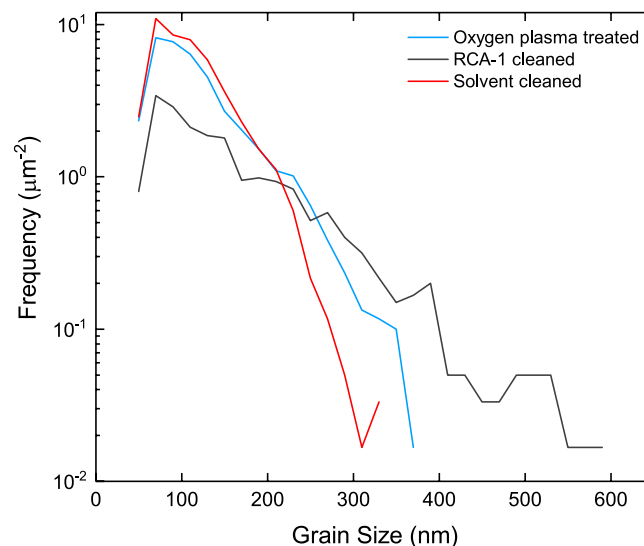


Figure 1. A plot displaying the grain size distribution for each diamond film.

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